



Product data sheet

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MAC97A6 THRU MAC97A8 HF

Semiconductor Compiance



SOT-89

Dealyaga	Pin assignment			
Package	1	2	3	
SOT-89	T1	T2	G	

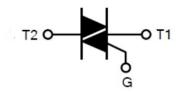
FEATURES

- Direct interfacing to logic level ICs
- Direct interfacing to low power gate drivers and microcontrollers
- High blocking voltage capability
- Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Very sensitive gate

APPLICATIONS

- General purpose bidirectional switching
- General purpose low power phase control
- General purpose low power switching
- Solid-state relay

SYMBOL:



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE		E	UNIT	
Popotitivo Pook Off State Voltagos		MAC97A6 400 MAC97A8 600		- V		
Repetitive Peak Off-State Voltages	V _{DRM} , V _{RRM}			600		
RMS on-State Current	I _{T(RMS)}		0.8		A	
Non-Repetitive Peak On-State Current	I _{TSM}		8		A	
l ² t for fusing	l ² t		0.32		A ² s	
		I		50		
Repetitive rate of rise of on-state current	alt/at	II		50		
after triggering	dIT/dt			50	- A/uS	
		IV		10	-	
Peak gate current	I _{GM}	1		A		
Peak Gate Voltage V _{GM}			5		V	
Peak Gate Power	P _{GM}	5		W		
Average Gate Power	P _{G(AV)}	0.1		W		
Operating junction temperature	TJ	+125		°C		
Storage Temperature	T _{STG}	T _{STG} -40 ~ +150		50	°C	

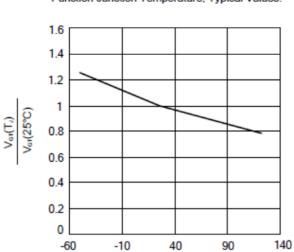


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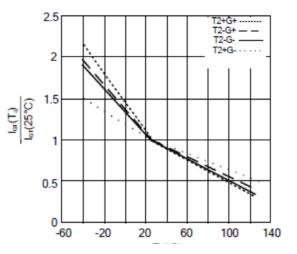
ELECTRICAL CHARACTERISTICS (TJ=25°C)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	MAX	UNITS
Peak Repetitive Forward or Reverse Blocking Current	I _{DRM} I _{RRM}	V_{AK} = Rated V_{DRM} or V_{RRM} ;			10	uA
			I		5.0	
Coto Triggor Current	I _{GT}	V _D =12V	II		5.0	mA
Gate Trigger Current		$I_{GT}=0.1A$	III		5.0	
			IV		7.0	
Gate Trigger Voltage	V _{GT}	$V_D=12V$, RL=100 Ω			2.0	V
Peak Forward On-State Voltage	V _{TM}	IT=1.0A,			1.7	V
			I		10	
Lielding Ourset		V _D =12V	II		20	
Holding Current	IL IL	I _G =0.1A,	III		10	- mA
			IV		10	
Latch Current	I _H	V _D =12V,IG=0.1A			10	mA
Critical Rate of Rise of Off-State Voltage	dV/dt	$V_{D}=67\%V_{DRM}, R_{GK}=1k\Omega,$		10		V/µs

ELECTRICAL CHARACTERISTIC CURVE



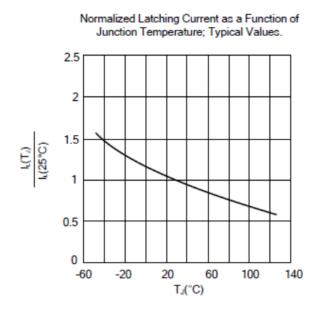
Normalized Gate Trigger Voltage as a of Function Junction Temperature; Typical Values. Normalized Gate Trigger Current as a Function of Junction Temperature; Typical Values.



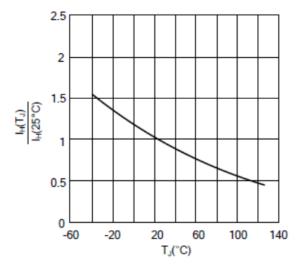


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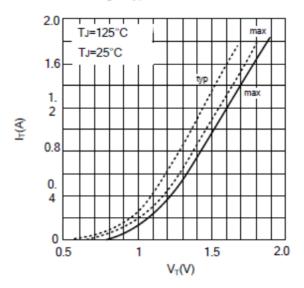
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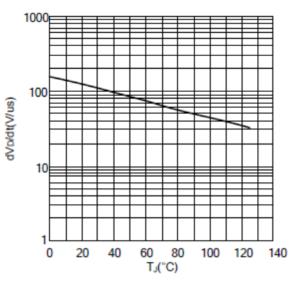
Normalized Holding Current as a Function of Junction Temperature; Typical Values.



On-State Current as a Function of On-State Voltage; Typical and Maximum Values.



Critical Rate of Rise of Off-State Voltage as a Function of Junction Temperature; Typical Values.



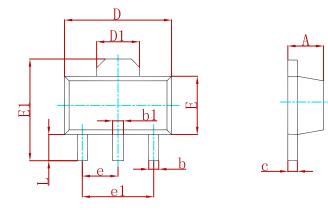


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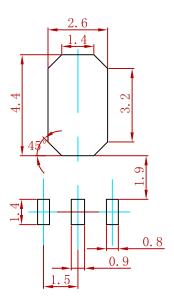
Rolls

PACKAGE MECHANICAL DATA



Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
А	1.400	1.600	0.055	0.063	
b	0.320	0.520	0.013	0.020	
b1	0.400	0.580	0.016	0.023	
С	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.550 REF.		0.061 REF.		
E	2.300	2.600	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
е	1.500 TYP.		0.060 TYP.		
e1	3.000 TYP.		0.118 TYP.		
L	0.900	1.200	0.035	0.047	

Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:±0.05mm.

3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
MAC97A6 THRU MAC97A8	SOT-89	1000



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